IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

KOHEI OKAMOTO ET AL.

Application No.: 10/573,308

Int'l Application No. PCT/JP2004/014809

Filed: September 30, 2004

For:
PROCESS FOR PRODUCING
THREE-DIMENSIONAL
STRUCTURE

May 4, 2007

Mail Stop PCT Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

SECOND INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the attached Form PTO-1449. Copies of the listed documents are provided.

CONCLUSION

It is respectfully requested that the above information be considered by the Examiner and that a copy of the attached Form PTO-1449 be returned indicating that such information has been considered.

Applicants' undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our address given below.

Respectfully submitted,

/Jason M. Okun/ Jason M. Okun Attorney for Applicants Registration No.: 48,512

FITZPATRICK, CELLA, HARPER & SCINTO 30 Rockefeller Plaza New York, New York 10112-3801

Facsimile: (212) 218-2200

FORM PTO 1449 (modified) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE			ATTY DOCKET NO. 03500.103088	APPLICATION NO. 10/573,308				
	F REFERENCES CITED BY APPLI (Use several sheets if necessary)	ICANT(S)	APPLICANT Kohei Okamoto et al.					
			FILING DATE September 30, 2004		GROUP 2	2873		
			U.S. PATENT DOCUMENTS					
*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE		
				0 1				
		FC	DREIGN PATENT DOCUMENTS					
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT		
	0'	THER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pag	es, Etc.)				
	N. Kawai et al., " Photonic Crystal	Confined Bar I," 86(11) Phy	nd Gap in an Air-Bridge Type sical Rev. Lett. 2289-92 (Mare	of Two-Dimer ch 2001).	nsional AlGa	aAs		
	M. Notomi et al., Photonic Band C	M. Notomi et al., "Drilled Alternating-Layer Three-Dimensional Photonic Crystals Having a Full Photonic Band Gap," 77(26) Appl. Phys. Lett. 4256-58 (December 2000).						
	Yurii A. Vlasov e	Yurii A. Vlasov et al., "On-Chip Natural Assembly of Silicon Photonic Bandgap Crystals," 414 Nature 289-93 (November 2001).						
			DATE COMMUNICATION					

'EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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